MAR 1 4 2006

# IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

**Serial No.:** 10/709,776

Conf. No.: 3775

Filing Date: 5/27/2004

2811 **Art Unit:** 

Applicant:

William G. America

Examiner:

Im, Junghwa M.

Title:

SEMICONDUCTOR DEVICE FORMED Docket No.: FIS920040083US1

BY IN-SITU MODIFICATION OF

(IBMF-0058)

DIELECTRIC LAYER AND RELATED

**METHODS** 

## **COMMISSIONER FOR PATENTS**

**DESTINATION FACSIMILE NUMBER:** 

571-273-8300

Transmitted herewith is:

Amendment in 7 pages

Amendment Transmittal Letter in 1 page

in the above identified application.

#### CERTIFICATION OF FACSIMILE TRANSMISSION

I hereby certify that this correspondence is being facsimile transmitted to the United States Patent and Trademark Office on the date shown below.

> Jennifer Kelly (Person transmitting this correspondence)

March 14, 2006

Date Signature

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AMENDMENT TRANSMITTAL LETTER				Attorney Docket No: FIS920040083US1	
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In Re Application of: William G. America

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2811

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Dkt. #: FJS920040083US1 (IBMF-0058)

Title: SEMICONDUCTOR DEVICE FORMED

Examiner:

Im, Junghwa M

BY IN-SITU MODIFICATION OF DIELECTRIC LAYER AND RELATED

**METHODS** 

Mail Stop Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

## **AMENDMENT**

Sir:

#### INTRODUCTORY COMMENTS I.

This paper is being filed in response to the Office Action dated December 14, 2005.

Please amend the above-referenced patent application as follows: